Sensor development and characterisation for Velo Upgrade

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15th Trento Workshop – Vienna 2020
LHCb
LHCb
Vertex Locator (Velo) upgrade

52 modules make up the Velo
All separately connected to the outside
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Each module consists of 12 ASICs, each with 65k pixels

This talk will mostly be focused on the sensors of the Velo
Currently modules are being produced, with the goal of mounting the Velo Upgrade before the start of first beam
Challenge for Velo

- 5.1 mm sensitive distance to beam
  - Up to $8 \times 10^{15} \text{ 1 MeV } n_{\text{eq}} \text{ cm}^{-2}$ (50 fb$^{-1}$)
  - Non-uniform irradiation (factor 50 difference over a single module)
- Operate in vacuum
- Extremely high data rate, up to 15.1 Gbit/s for hottest module
- Efficiency at least 99%
- Charge collection for MIP > 6000 e$^{-}$ after 50 fb$^{-1}$
- Timewalk < 25 ns
Testing program

- Prototypes used Timepix3 (pitch of 55 µm) – Time-over-Threshold allows charge measurements, and Time-of-Arrival allows time measurement (1.56 ns)

- The Velo sensors must withstand 370 Mrad ~ 8 x 10^{15} 1 MeV n_{eq} cm^{-2}
  - The ATLAS IBL – at 550 fb^{-1} – expects 3.3 x 10^{15} 1 MeV n_{eq} cm^{-2} or 160 MRad

- Resolution, efficiency, charge collection:
  - Measurements at the SPS using the Timepix3 telescope

- Calibrations performed in the lab (not discussed in this talk):
  - Test pulses
  - Radioactive sources
  - Synchrotron x-rays
Sensor prototypes

Hamamatsu (HPK):
n-on-p, 200 µm thick, 450(600) µm pixel-to-edge,
35 (39) µm implant size

Micron:
n-on-p, 200 µm thick, 450(250) µm pixel-to-edge,
36 µm implant size

Micron:
n-on-n, 150 µm thick, 450(250, 150) µm pixel-to-edge,
36 µm implant size
Irradiation campaign

**IRRAD**
Protons, 24 GeV
Non-uniform:
Up to $8 \times 10^{15}$ 1 MeV $n_{eq}$ cm$^{-2}$

**KIT**
Protons, 24 MeV
Non-uniform:
Up to $8 \times 10^{15}$ 1 MeV $n_{eq}$ cm$^{-2}$

**JSI**
Neutrons
Uniform:
$4 \times 10^{15}$ or $8 \times 10^{15}$ 1 MeV $n_{eq}$ cm$^{-2}$
Timepix3 Telescope

• 8 Timepix3 planes
  • Particle track can be reconstructed through all 8 planes

• Pointing resolution:
  \[ \sigma_x = 1.69 \pm 0.16 \mu m \]
  \[ \sigma_y = 1.55 \pm 0.16 \mu m \]

• Time resolution:
  Either using two scintillators (\( \sigma_t = 390 \, ps \), \( \sigma_t = 190 \, ps \))
  Or using the time of Timepix3 hits (\( \sigma_t = 350 \, ps \) or \( \sigma_t = 271 \, ps \), soon to be submitted)

Efficiencies

- First requirement: efficiency > 99%
- Achieved for > 800 V
- Observed: larger implant increases efficiency

Corners recover at 800 V
Intra-pixel collected charge

• Using tracking of telescope, the measured charge within the pixel can be determined.

HPK n-on-p (35 µm) – 800 V

24 GeV proton irradiation
Intra-pixel collected charge

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HPK n-on-p (35 µm) – 800 V

24 GeV proton irradiation
Intra-pixel collected charge

- Using tracking of telescope, the measured charge within the pixel can be determined.
Cluster size

- Mainly cluster size 2 & 3 around the corner
- The dip seems to be due to a threshold effect

Due to cluster size 2 & 3
Collected charge

• Collected as function of voltage and fluence
• Overall: less charge for higher fluence
• Charge multiplication observed for 2 sensor
  • Other sensors could not reach 1000 V or started to become too noisy

• Goal achieved of MIP > 6000 e⁻ for > 900 V at full fluence
Collected charge

- Investigation of intra-pixel behavior for charge multiplication
- Multiplication onset at $6.1 \times 10^{15}$ $1 \text{ MeV} \, n_{\text{eq}} \text{ cm}^{-2}$ at 1000 V
- Only observed in proton irradiated sensors
- Observed in only 2 out of 4 (IRRAD) sensors
  - Other sensors could not reach 1000 V
Timing studies

- Required to be less than bunch crossing rate (25 ns)
- For > 600 V, timewalk is small enough
- Time resolution decreases with higher fluence

Dall’Occo, E. (2016). Sensor Developments for the LHCb VELO Upgrade. 4th BTTB Workshop
New Velo, new sensors (R&D work at Nikhef)

Upgrade 2 for Velo is scheduled for 2031, will require new sensors
Separate R&D work ongoing at Nikhef (not specifically for LHCb)

- Thin planar 50 µm (with thanks to CLIC)
  - p-on-n, Advacam
  - Depletion voltage 15-20 V
  - Bias 90 V
  - $\sigma_t = 588\, \text{ps}$ (best hits, with ASIC contribution)

- 3D 285 µm (with thanks to R. Bates)
  - n-type bulk, CNM-IBM
  - Depletion voltage 20 V
  - Bias 60 V
  - $\sigma_t = 590\, \text{ps}$ (best hits, with ASIC contribution)

Summary & Outlook

• Sensors from HPK and Micron have been tested with non-uniform irradiation
• Sensors have been found to withstand the radiation up to $8 \times 10^{15}$ 1 MeV $n_{eq}$ cm$^{-2}$ while achieving the minimum requirements set

• Main findings:
  • Large implants for better efficiency
  • High voltage required to large enough signals (mitigate timewalk)

• Working on Upgrade 2 (2031)
  • New sensor designs/types?
  • 3D, LGAD, AC-LGAD?
Thank you for the attention!

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Backup: Timewalk

- Due to a lower charges taking longer to reach threshold
Backup: Timepix3

Time [ns] = 25 * ToA – 1.56 * fToA = 364.1 ns

1. Voltage
2. Threshold
3. Time [ns] = 25 * ToA – 1.56 * fToA = 364.1 ns
4. 40 MHz
5. 640 MHz
6. ToT
7. Global ToA
8. ToA

Δ = ToT

Δ = ToA

Δ = Time [ns] = 25 * ToA – 1.56 * fToA = 364.1 ns
Backup: Timepix3 telescope
Hit resolution

- Important to achieve small error on IP
- Hit resolution determined before (top) and after (bottom) irradiation
- Systematically worse after irradiation

Backup: Additional sensors – Micron n-on-n

Fluence: 5.47e15-6.10e15

- Micron n-on-n
Backup: Additional sensors – Micron n-on-p

Fluence: 5.46e15-6.07e15

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